Rectifier Diode



Preliminary Information

DS6066 - 12 December 2011 (LN28906)

FEATURES

- Double Side Cooling
- High Surge Capability

KEY PARAMETERS

V_{RRM}	9000V
I _{F(AV)}	557A
I _{FSM}	10000A

VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages V _{RRM} V	Conditions
DRD590G90 DRD590G85 DRD590G80	9000 8500 8000	$V_{RSM} = V_{RRM} + 100V$

(See Package Details for further information)

Fig. 1 Package outline

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

DRD590G85 for a 8500V device



CURRENT RATINGS

$T_{case} = 75$ °C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units		
Double Si	Double Side Cooled					
$I_{F(AV)}$	Mean forward current	Half wave resistive load	684	А		
I _{F(RMS)}	RMS value	-	1074	Α		
I _F	Continuous (direct) on-state current	-	1019	А		
Single Sid	de Cooled (Anode side)	,	1			
I _{F(AV)}	Mean forward current	Half wave resistive load	461	А		
I _{F(RMS)}	RMS value	-	724	А		
I _F	Continuous (direct) on-state current	-	654	А		

T_{case} = 100°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units		
Double Si	Double Side Cooled					
$I_{F(AV)}$	Mean forward current	Half wave resistive load	557	А		
I _{F(RMS)}	RMS value	-	876	Α		
I _F	Continuous (direct) on-state current	-	819	Α		
Single Sid	de Cooled (Anode side)					
I _{F(AV)}	Mean forward current	Half wave resistive load	372	Α		
I _{F(RMS)}	RMS value	-	584	Α		
l _F	Continuous (direct) on-state current	-	517	Α		



SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	8	kA
l ² t	I ² t for fusing	$V_R = 50\% V_{RRM} - \frac{1}{4}$ sine	0.32	MA ² s
I _{FSM}	Surge (non-repetitive) on-state current	10ms half sine, T _{case} = 150°C	10	kA
l ² t	I ² t for fusing	$V_R = 0$	0.5	MA ² s

THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions		Min.	Max.	Units
$R_{\text{th(j-c)}}$	Thermal resistance – junction to case	Double side cooled	DC	-	0.032	°C/W
		Single side cooled	Anode DC	-	0.064	°C/W
			Cathode DC	-	0.064	°C/W
R _{th(c-h)}	Thermal resistance – case to heatsink	Clamping force 43kN	Double side	-	.008	°C/W
		(with mounting compound)	Single side	-	.016	°C/W
T _{vj}	Virtual junction temperature			-	160	°C
T_{stg}	Storage temperature range			-55	175	°C
F _m	Clamping force			11	13	kN

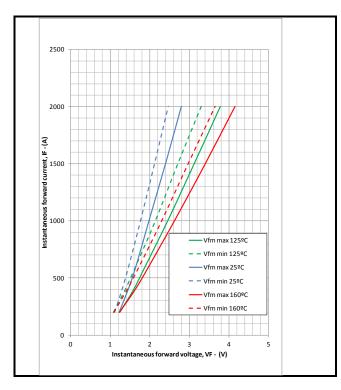
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CHARACTERISTICS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
V_{FM}	Forward voltage	At 1200A peak, T _{case} = 160°C	-	2.95	V
I _{RM}	Peak reverse current	At V _{DRM} , T _{case} = 160°C	-	100	mA
Qs	Total stored charge	I _F = 2000A, dI _{RR} /dt =5A/μs	3300	5000	μC
Irr	Peak reverse recovery current	$T_{case} = 160$ °C, $V_R = 100$ V	140	170	Α
V _{TO}	Threshold voltage	At T _{vj} = 160°C	-	1.0	V
r _T	Slope resistance	At T _{vj} = 160°C	-	1.575	mΩ

CURVES



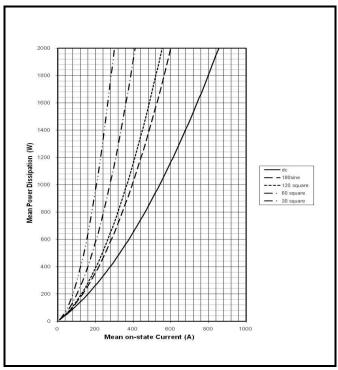


Fig.2 Maximum & minimum on-state characteristics

Fig.3 Dissipation curves

 V_{TM} EQUATION

 $V_{TM} = A + BIn (I_T) + C.I_T + D.\sqrt{I_T}$

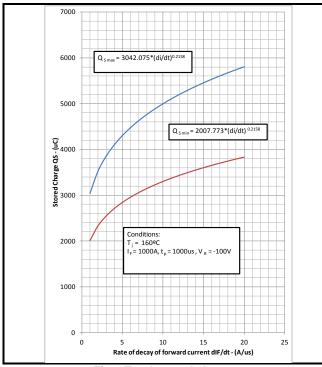
Where A = -0.675901B = 0.3995

C = 0.001796

D = -0.040301

these values are valid for $T_j = 160^{\circ}\text{C}$ for $I_F 200\text{A}$ to 2000A





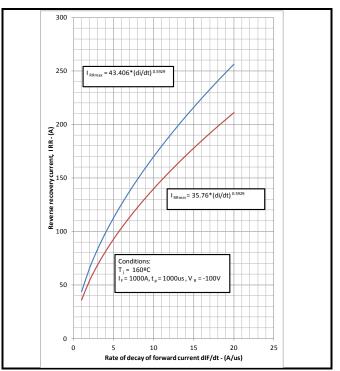
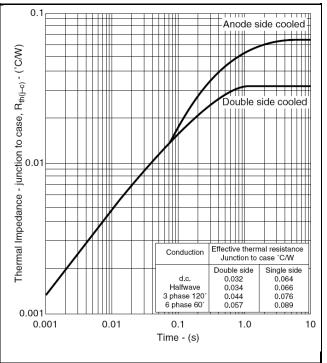
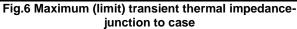


Fig.4 Total stored charge

Fig.5 Maximum reverse recovery current

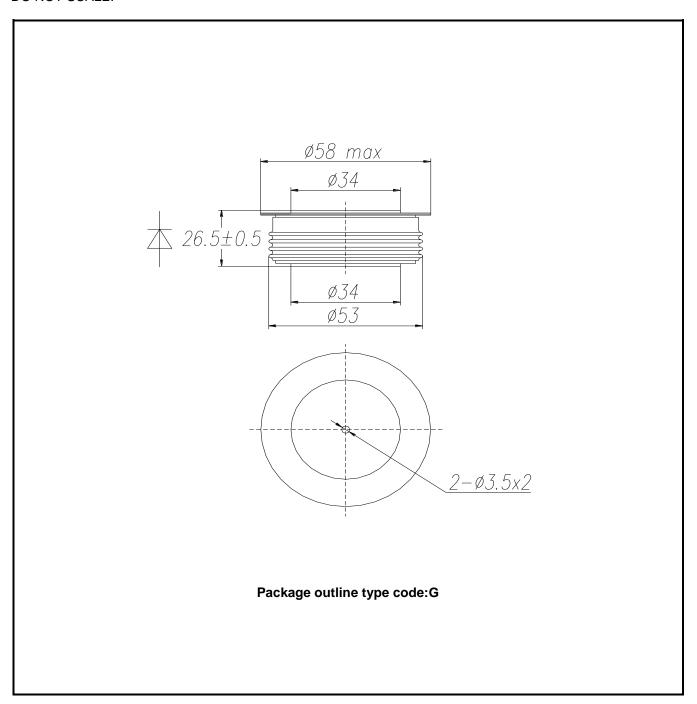






PACKAGE DETAILS

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





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